

TOSHIBA Photocoupler GaAs Ired &amp; Photo-Transistor

**TLP504A, TLP504A-2**

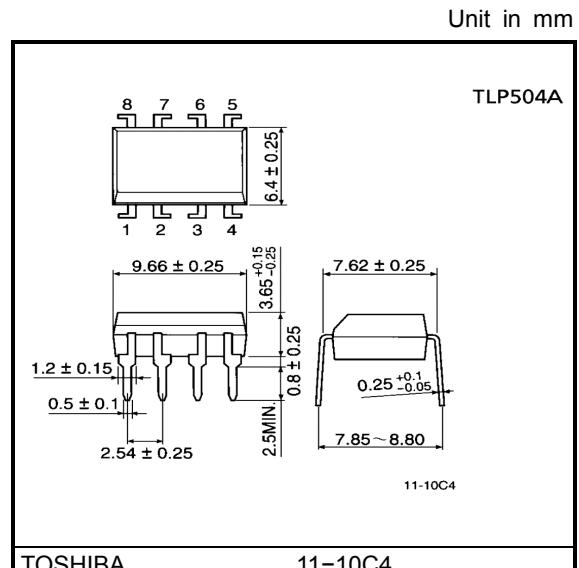
Programmable Controllers  
AC / DC-Input Module  
Solid State Relay

The TOSHIBA TLP504A and TLP504A-2 consists of a photo-transistor optically coupled to a gallium arsenide infrared emitting diode.

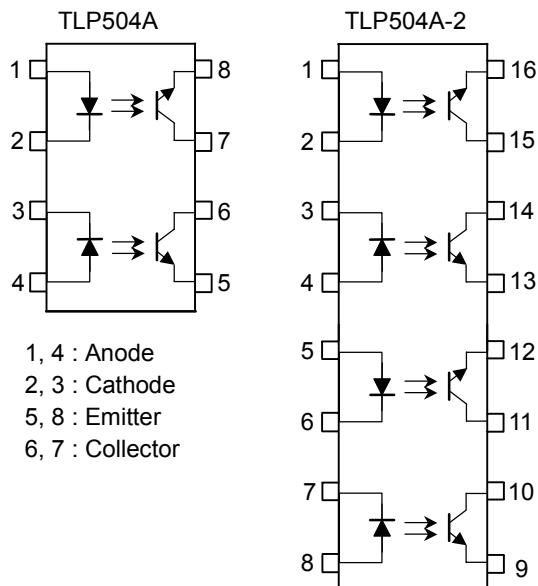
The TLP504A offers two isolated channels in a eight lead plastic DIP package, while the TLP504A-2 provides four isolated channels in a sixteen lead plastic DIP package.

- Collector-emitter voltage: 55 V (min.)
- Current transfer ratio: 50% (min.)  
Rank GB: 100% (min.)
- Isolation voltage: 2500 Vrms (min.)
- UL recognized: UL1577,

File no. E67349

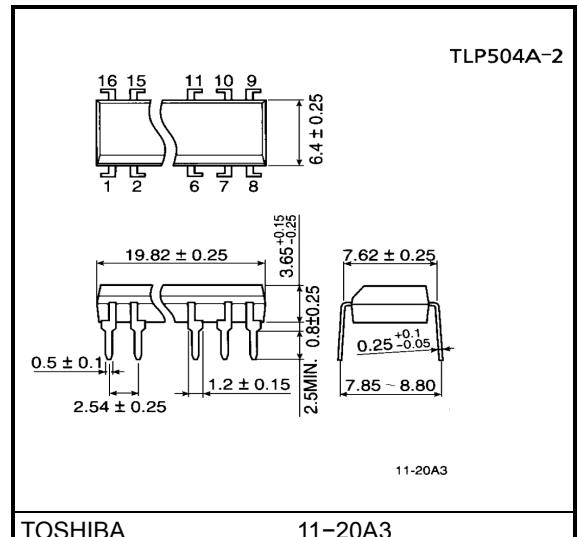


Weight: 0.54 g

**Pin Configurations (top view)**

1, 4 : Anode  
2, 3 : Cathode  
5, 8 : Emitter  
6, 7 : Collector

1, 4, 5, 8 : Anode  
2, 3, 6, 7 : Cathode  
9, 12, 13, 16 : Emitter  
10, 11, 14, 15 : Collector



Weight: 1.1 g

Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Characteristic	Symbol	Rating		Unit
		TLP504A	TLP504A-2	
LED	Forward current	$I_F$	60	mA
	Forward current derating	$\Delta I_F / ^\circ\text{C}$	-0.7 ( $T_a \geq 39^\circ\text{C}$ )	mA / $^\circ\text{C}$
	Pulse forward current	$I_{FP}$	1 (100 $\mu\text{s}$ pulse, 100pps)	A
	Reverse voltage	$V_R$	5	V
	Junction temperature	$T_j$	125	$^\circ\text{C}$
Detector	Collector-emitter voltage	$V_{CEO}$	55	V
	Emitter-collector voltage	$V_{ECO}$	7	V
	Collector current	$I_C$	50	mA
	Collector power dissipation (1 circuit)	$P_C$	150	mW
	Collector power dissipation derating (1 circuit $T_a \geq 25^\circ\text{C}$ )	$\Delta P_C / ^\circ\text{C}$	-1.5	mW / $^\circ\text{C}$
	Junction temperature	$T_j$	125	$^\circ\text{C}$
Storage temperature range	$T_{stg}$	$-55\text{--}150$		$^\circ\text{C}$
Operating temperature range	$T_{opr}$	$-55\text{--}100$		$^\circ\text{C}$
Lead soldering temperature	$T_{sol}$	260 (10 s)		$^\circ\text{C}$
Total package power dissipation	$R_T$	250	150	mW
Total package power dissipation derating ( $T_a \geq 25^\circ\text{C}$ )	$\Delta P_T / ^\circ\text{C}$	-2.5	-1.5	mW / $^\circ\text{C}$
Isolation voltage	$BV_S$	2500 (AC, 1min., R.H. $\leq 60\%$ ) (Note 1)		Vrms

(Note 1) Device considered a two terminal device: LED side pins shorted together and detector side pins shorted together.

## Recommended Operating Conditions

Characteristics	Symbol	Min.	Typ.	Max.	Unit
Supply voltage	$V_{CC}$	—	5	24	V
Forward current	$I_F$	—	16	20	mA
Collector current	$I_C$	—	1	10	mA
Operating temperature	$T_{opr}$	-25	—	85	$^\circ\text{C}$

**Individual Electrical Characteristics (Ta = 25°C)**

Characteristic		Symbol	Test Condition	Min.	Typ.	Max.	Unit
LED	Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 10 mA	1.0	1.15	1.3	V
	Reverse current	I <sub>R</sub>	V <sub>R</sub> = 5 V	—	—	10	µA
	Capacitance	C <sub>T</sub>	V = 0, f = 1 MHz	—	30	—	pF
Detector	Collector-emitter breakdown voltage	V <sub>(BR) CEO</sub>	I <sub>C</sub> = 0.5 mA	55	—	—	V
	Emitter-collector breakdown voltage	V <sub>(BR) ECO</sub>	I <sub>E</sub> = 0.1 mA	7	—	—	V
	Collector dark current	I <sub>CEO</sub>	V <sub>CE</sub> = 24 V	—	10	100	nA
			V <sub>CE</sub> = 24 V, Ta = 85°C	—	2	50	µA
	Capacitance collector to emitter	C <sub>CE</sub>	V = 0, f = 1 MHz	—	10	—	pF

**Coupled Electrical Characteristics (Ta = 25°C)**

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Current transfer ratio	I <sub>C</sub> / I <sub>F</sub>	I <sub>F</sub> = 5 mA, V <sub>CE</sub> = 5 V Rank GB	50	—	600	%
			100	—	600	
Saturated CTR	I <sub>C</sub> / I <sub>F</sub> (sat)	I <sub>F</sub> = 1 mA, V <sub>CE</sub> = 0.4 V Rank GB	—	60	—	%
			30	—	—	
Collector-emitter saturation voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> = 2.4 mA, I <sub>F</sub> = 8 mA	—	—	0.4	V
		I <sub>C</sub> = 0.2 mA, I <sub>F</sub> = 1 mA Rank GB	—	0.2	—	
			—	—	0.4	

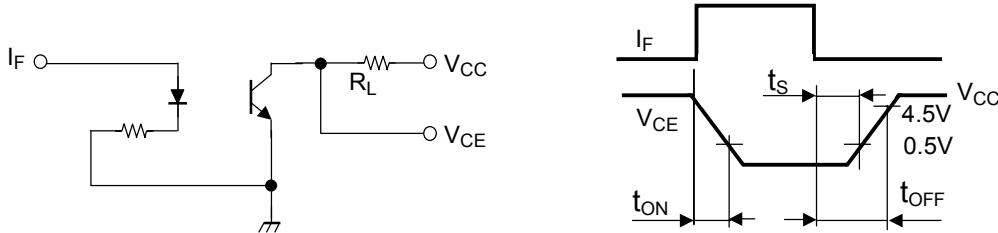
**Isolation Characteristics (Ta = 25°C)**

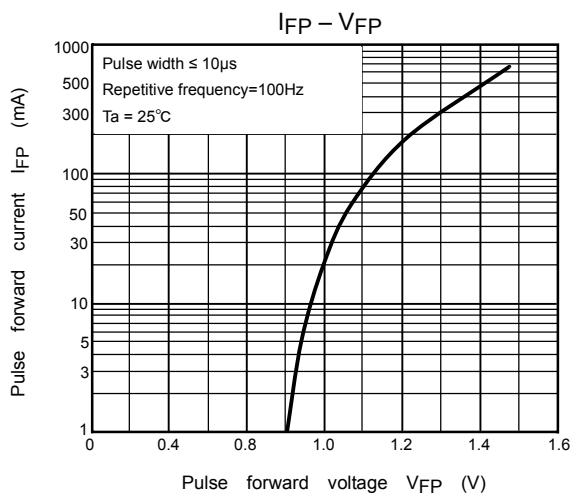
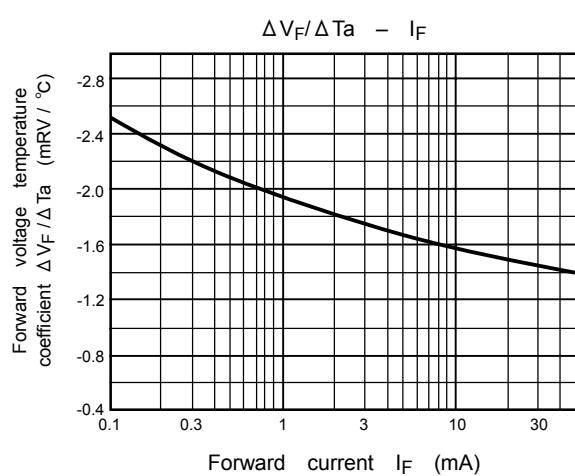
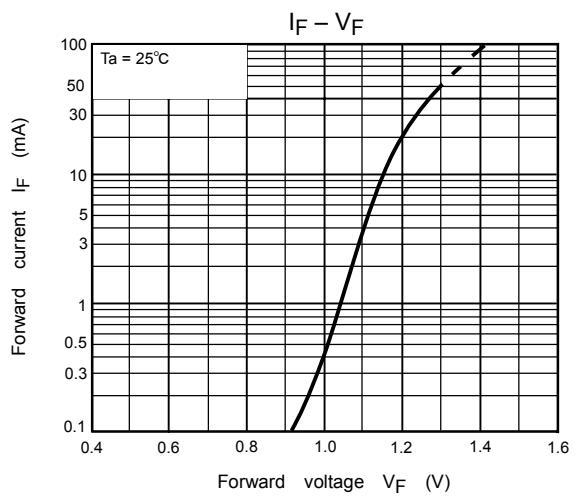
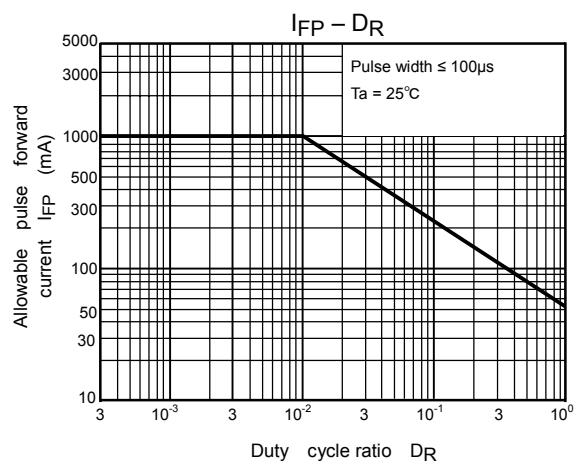
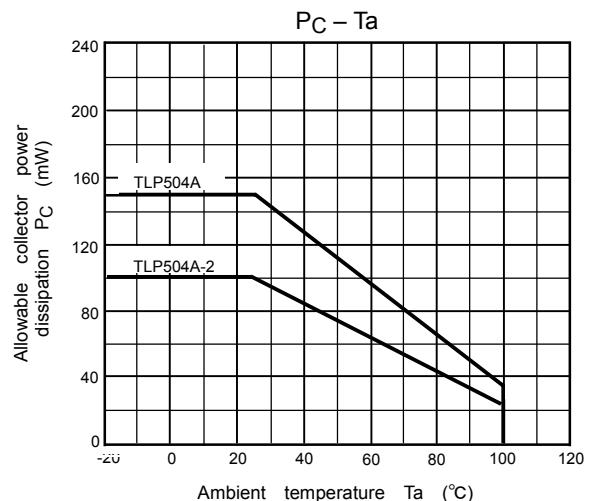
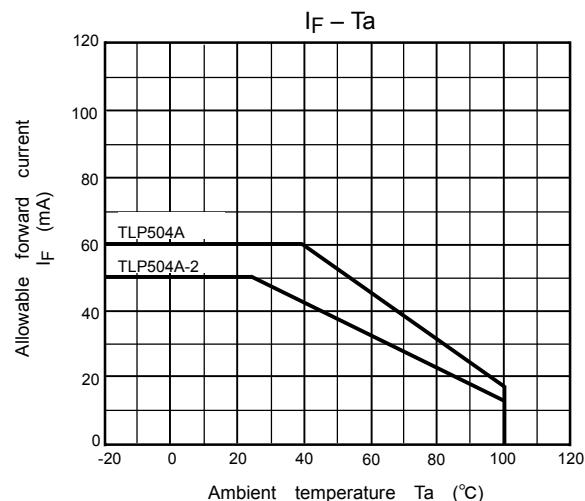
Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Capacitance input to output	C <sub>S</sub>	V <sub>S</sub> = 0, f = 1 MHz	—	0.8	—	pF
Isolation resistance	R <sub>S</sub>	V <sub>S</sub> = 500 V	5×10 <sup>10</sup>	10 <sup>14</sup>	—	Ω
Isolation voltage	BVs	AC, 1 minute	2500	—	—	Vrms
		AC, 1 second, in oil	—	5000	—	
		DC, 1 minute, in oil	—	5000	—	Vdc

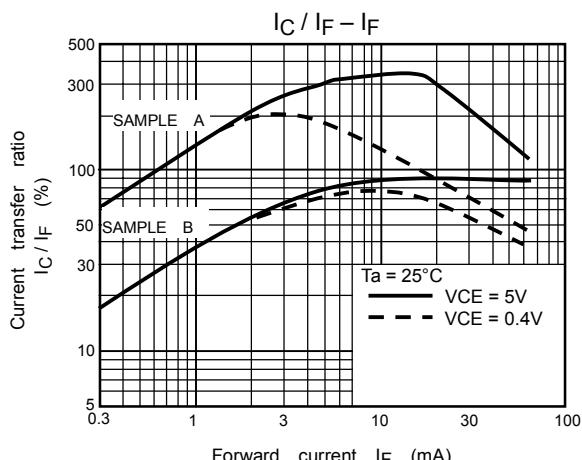
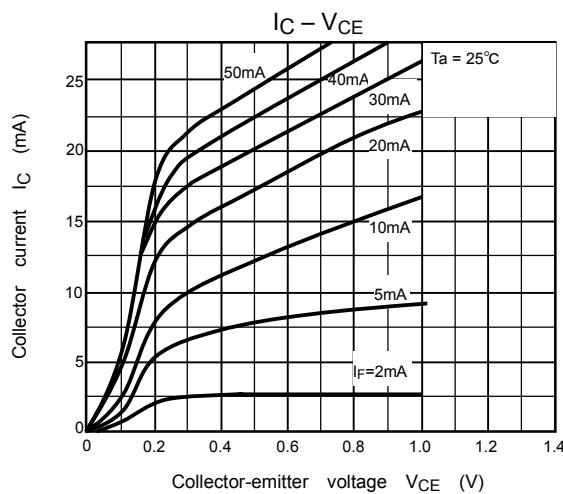
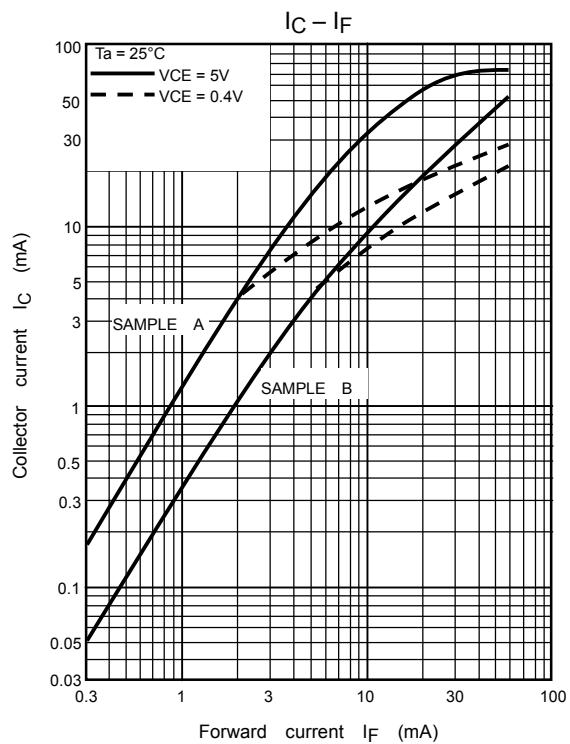
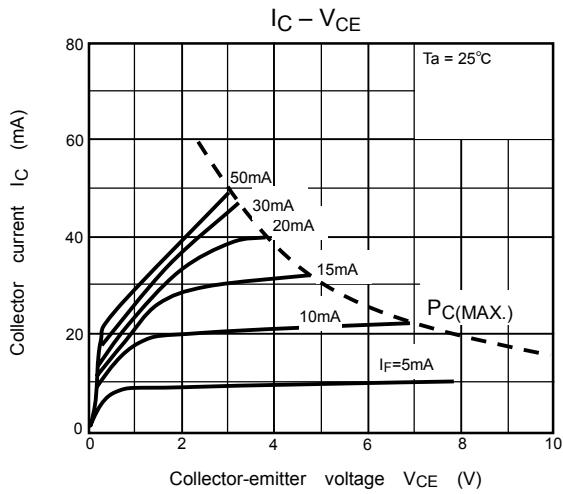
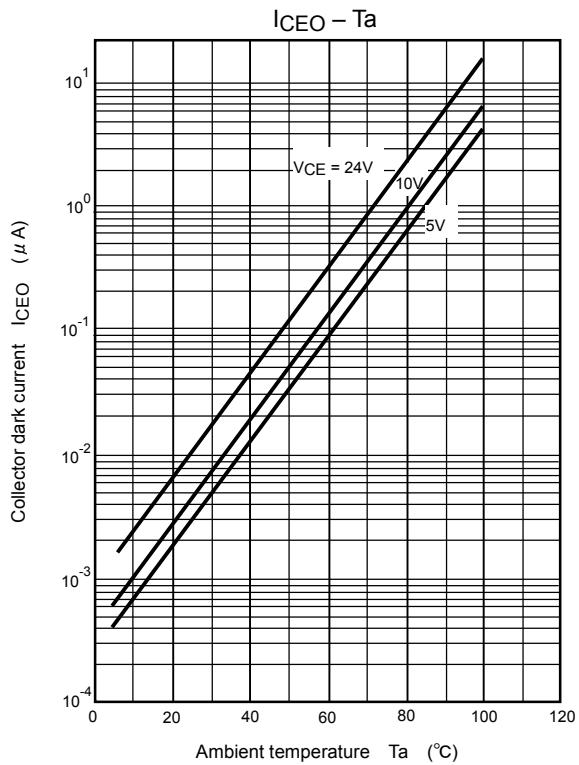
Switching Characteristics ( $T_a = 25^\circ\text{C}$ )

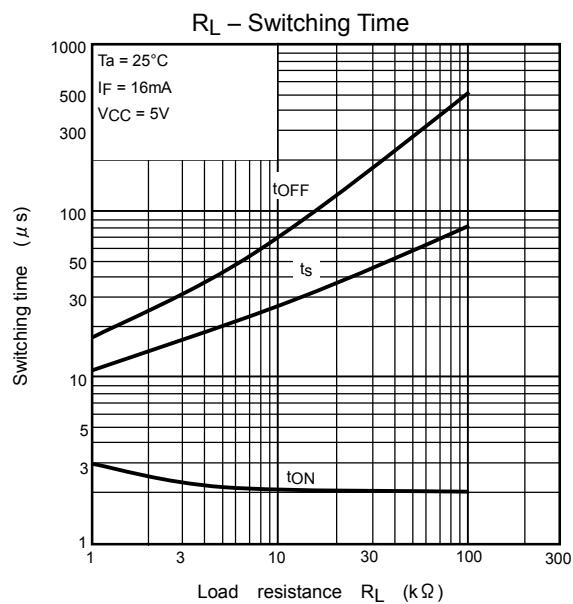
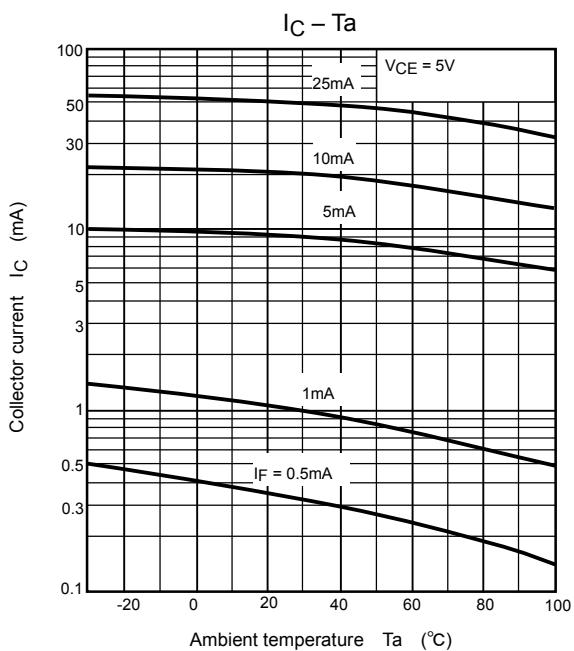
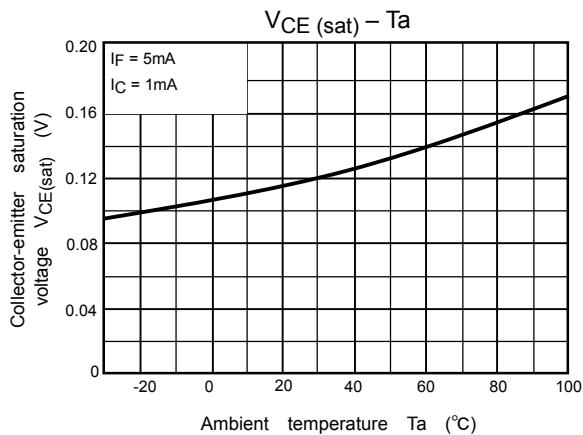
Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Rise time	$t_r$	$V_{CC} = 10\text{ V}, I_C = 2\text{ mA}$ $R_L = 100\Omega$	—	2	—	$\mu\text{s}$
Fall time	$t_f$		—	3	—	
Turn-on time	$t_{on}$		—	3	—	
Turn-off time	$t_{off}$		—	3	—	
Turn-on time	$t_{ON}$	$R_L = 1.9\text{ k}\Omega$ $V_{CC} = 5\text{ V}, I_F = 16\text{ mA}$ (Fig.1)	—	2	—	$\mu\text{s}$
Storage time	$t_s$		—	15	—	
Turn-off time	$t_{OFF}$		—	25	—	

Fig. 1 Switching time test circuit









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